

HMS88T1608L/16L

8-BIT CMOS MCU BASED SAFEGUARDED SMARTCARD IC WITH 8176/16384 BYTES EEPROM

FEATURES

- Extended voltage Operation
 - V_{CC} Range: 2.7V ~ 5.5V
- 8 Bit Architecture CPU
- 16K Bytes User ROM, Sector Combinative
- 2.7K Bytes System ROM
- 384 Bytes RAM
- 8176/16384 Bytes EEPROM, Sector Combinative:
 - Highly Reliable CMOS EEPROM Technology
 - 10 Years Data Retention
 - 300,000 Erase/Write Cycles Endurance
 - Protected One Time Programmable Block (32 or 64 Bytes)
 - 1 to 32 Bytes Block Erase or Write in a Single Cycle Programming
- Serial Access, ISO 7816-3 Compatible
- Standby Mode for Power Saving
- Up to 5 MHz Internal Operating Frequency
- Very High Security Features Including EEP-ROM flash erase
- Contact Assignment Compatible ISO7816-2
- ESD Protection Greater than 5,000V
- 2 Operating Configurations
 - Issuer
 - User
- Meets GSM 11.11 and 11.12 Specifications

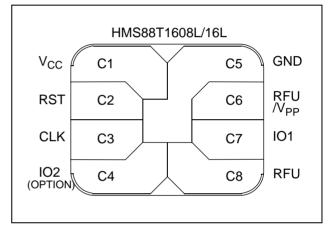


Figure 1. Pin Configuration

| V _{CC} | Supply Voltage |
|-----------------|---------------------------|
| RST | Reset |
| CLK | Clock |
| RFU | Reserved for future |
| GND | Ground |
| I/O1 | Data Input/Output |
| I/O2 | Data Input/Output(Option) |

Table 2. Contact Format

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INTRODUCTION

The HMS88T1608L/16L, a member of the standard HMS88T16XYZ family, are a serial access microcontrollers especially designed for very large volume and cost competitive smart cards applications.

The HMS88T1608L/16L are based on an 8 bit CPU core and include on chip memories: 384 bytes RAM, 16K bytes ROM, 8176/16384 bytes EEPROM structured in two main sectors to be used in different combinations, as described below.

Reliability data related to the HMS88T1608L/16L products manufactured using Hynix $0.7\mu m$ CMOS EEPROM technology guarantees data retention up to 10 years and endurance up to 300,000 erase/write cycles.

As all the other HMS88T16XYZ family members, the HMS88T1608L/16L are fully compatible with the ISO standards for smart card applications.

The HMS88T1608L/16L can be delivered as: either in sawn or un-sawn 6inch wafers, 180 micron thickness as well as in micromodule package.

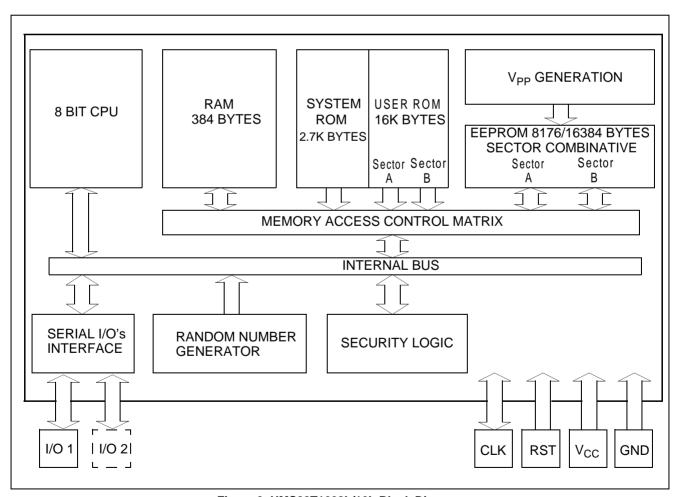


Figure 3. HMS88T1608L/16L Block Diagram